

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

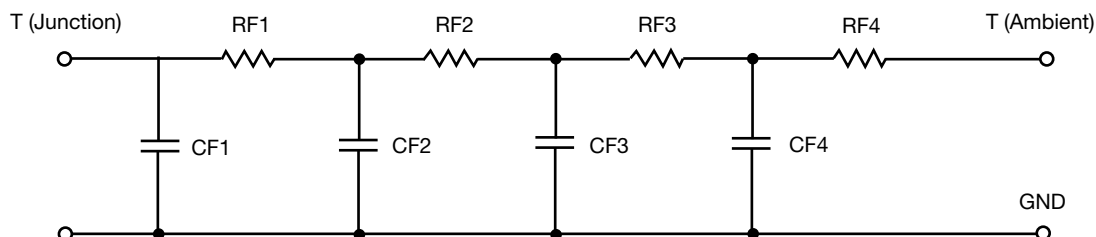


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	13.2271	25.8910m	N/A
RT2	6.0509	443.0914m	N/A
RT3	2.8014	578.4139m	N/A
RT4	31.1887	149.5618m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.1020	3.4682	N/A
CT2	112.1365m	199.4418m	N/A
CT3	32.1935m	21.3246m	N/A
CT4	3.2166	1.5359m	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION

R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	5.9102	148.0206m	N/A
RF2	9.2682	424.8462m	N/A
RF3	26.8208	204.3297m	N/A
RF4	11.7265	416.8700m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	23.6931m	1.1449m	N/A
CF2	233.8259m	13.5850m	N/A
CF3	1.1772	17.4906m	N/A
CF4	9.6435	118.7339m	N/A

Note

N/A indicates not applicable

